NSN 5961-00-181-0661

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
Between 0.140 inches and 0.205 inches
Terminal Length:
Between 0.600 inches and 1.500 inches
Overall Diameter:
Between 0.060 inches and 0.110 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1000.0 working peak reverse voltage
Current Rating Per Characteristic:
1.00 amperes forward current, total rms megahertz and 30.00 amperes forward current, average preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Test Data Document:
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0
Mil-std (military Standard):
Mil-prf-19500 spec.